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Intel[®] Enpirion[®] Power Solutions EM2120x01QI 20A PowerSoC

Step-Down DC-DC Switching Converter with Integrated Inductor, Featuring Digital Control with PMBus[™] v1.2 Compliant Interface

Description

The EM2120 is a fully integrated 20A PowerSoC synchronous buck converter. It features an advanced digital controller, gate drivers, synchronous MOSFET switches, and a high-performance inductor. Only input and output filter capacitors and a few small signal components are required for a complete solution. A PMBus version 1.2 compliant interface provides setup, control, and telemetry.

Differential remote sensing and $\pm 0.5\%$ set-point accuracy provides precise regulation over line, load and temperature variation. Very low ripple further reduces accuracy uncertainty to provide best in class static regulation for today's FPGAs, ASICs, processors, and DDR memory devices.

The EM2120 may be used in standalone mode or utilizing the PMBus interface for a high degree of flexibility and programmability. Advanced digital control techniques ensure stability and excellent dynamic performance, and eliminate the need for external compensation components. The PC-based Intel Enpirion Digital Power Configurator provides a user-friendly and easy-to-use interface to the device for communication and configuration.

The EM2120 features high conversion efficiency and superior thermal performance to minimize thermal de-rating limitations, which is key to product reliability and longevity.

Features

- Integrated inductor, FETs, and digital controller
- Wide 4.5V to 16V V_{IN} range
- 0.7V to 5V VOUT range
- 20A continuous current with no thermal de-rating
- High efficiency in 11mm x 17mm x 6.76mm QFN
 package

 \circ 95% efficiency at V_{IN} = 5V, V_{OUT} = 3.3V \circ 90% efficiency at V_{IN} = 12V, V_{OUT} = 1.2V

- Optimized total solution size of only 365 mm²
- Meets all high-performance FPGA requirements

 Digital loop for best in class transient response
 0.5% set-point over line, load, and temperature
 Output ripple as low as 10 mV peak-peak
 Differential remote sensing
 Monotonic startup into pre-bias output
 Optimized FPGA configs stored in NVM
- Programmable through PMBus[™]
 oV_{OUT} margining, startup and shutdown delays
 oProgrammable warnings, faults and response
- Ability to operate without PMBus[™]
 ○RVSET resistor for programmable V_{OUT}
 ○RTUNE resistor for single resistor compensation
- Tracking pin for complex sequencing
- RoHS compliant, MSL level 3, 260°C reflow

Applications

- High performance FPGA supply rails
- ASIC and processor supply rails
- High density double data rate (DDR) memory VDDQ rails

Ordering Information

Part Number	Supported V _{OUT} Range	Package Markings	T _{AMBIENT} Rating (°C)	Package Description	
EM2120L01QI	0.7V to 1.325V	M2120L	-40 to +85	17 mm x 11 mm x 6.76 mm QFN104 provided in 112 units per tray	
EM2120H01QI	1.35V to 5V	M2120H	-40 to +85	17 mm x 11 mm x 6.76 mm QFN104 provided in 112 units per tray	
EVB-EM2120L01	0.7V to 1.325V	Evaluation b	oard; 20A sing	gle phase	
EVB-EM2120H01	1.35V to 5V	Evaluation board; 20A single phase			
EVI-EM2COMIF	EVI-EM2COMIF GUI interface dongle				

Table 1

Packing and Marking Information: www.altera.com/support/reliability/packing/rel-packing-and-marking.html

Pin Assignments

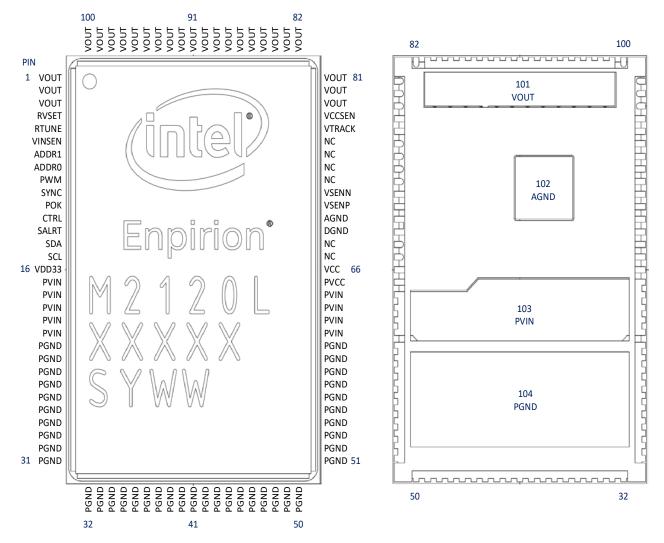


Figure 1: Pin Out Diagram

Data Sheet | Intel Enpirion Power Solutions: EM2120 Pin Description

Table 2

PIN	NAME	I/O	FUNCTION
1,2,3, 79-101	VOUT	Regulated Output	Regulated output voltage. Decouple to PGND with appropriate filter capacitors
4	RVSET	Analog I/O	A resistor from RVSET to AGND; and can be used to program the V _{OUT} set-point. Using 1% tolerance or better resistor. See Table 8 and
			Table 9 for more information.
5	RTUNE	Analog I/O	A resistor from RTUNE to AGND; and can be used to tune the transient compensator for the amount of output capacitance. Using 1% tolerance or better resistor. See Table 10 and
			Table 11 for more information.
6	VINSEN	Analog Input	Single-ended input voltage sense (relative to AGND).
7	ADDR1	Analog I/O	A resistor from ADDR1 to AGND; and can be used to set the PMBus [™] address. Use a 1% tolerance or better resistor.
8	ADDRO	Analog I/O	A resistor from ADDR0 to AGND; and can be used to set the PMBus [™] address. Use a 1% tolerance or better resistor.
9	PWM	PWM	PWM signal test pin.
10	SYNC	Digital I/O	PWM synchronization signal
11	РОК	Digital I/O	Power OK is selectable as a push-pull output or an open drain transistor for power system state indication. See the Power OK description for details
12	CTRL	Digital Input	PMBus-compatible control pin with programmable functionality. CTRL should never be left floating if enabled in Configuration. The default configuration is for V _{OUT} to be on with CTRL high (positive edge)
13	SALRT	Digital Output	PMBus™ alert line.
14	SDA	Digital I/O	PMBus™ serial data I/O.
15	SCL	Digital Input	PMBus™ serial clock input.
16	VDD33	Output	3.3V output of the internal LDO. May be used as pull-up supply for PMBus™ pins and CTRL pin.
17-21, 61-64, 103	PVIN	Input Supply	Input supply for MOSFET switches. Decouple to PGND with appropriate filter capacitors. Refer to Recommended Application Circuit section for more details.
22-60, 104	PGND	Ground	Power ground. Ground for MOSFET switches.
65	PVCC	Input Supply	5.0V supply voltage for driver circuitry. Decouple to PGND using a 2.2 μ F MLCC high quality ceramic capacitor.

Data Sheet | Intel Enpirion Power Solutions: EM2120

PIN	NAME	I/O	FUNCTION
66	VCC	Input Supply	5.0V supply voltage for analog circuitry.
67,68, 73-76	NC	NC	No connect. Do not connect to any signal, supply, or ground.
69	DGND	Ground	Digital ground. Connect to AGND pin directly.
70, 102	AGND	Ground	Analog ground. Connect to system ground plane. Refer to layout section for more details on grounding.
71	VSENP	Analog Input	Differential output voltage sense input (positive).
72	VSENN	Analog Input	Differential output voltage sense input (negative).
77	VTRACK	Analog Input	Voltage tracking reference input if EM2120 is configured for voltage tracking mode. May remain floating if not used. If enabled but not used, connect to VDD33 using a 10kΩ resistor. VTRACK is not enabled in the default configuration.
78	VCCSEN	Analog Input	Single-ended VCC voltage sense (relative to AGND)

Absolute Maximum Ratings

CAUTION: Absolute Maximum ratings are stress ratings only. Functional operation beyond the recommended operating conditions is not implied. Stress beyond the absolute maximum ratings may impair device life. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Voltage measurements are referenced to AGND.

Absolute Maximum Pin Ratings

	Table 5			
PARAMETER	SYMBOL	MIN	MAX	UNITS
Supply voltage PVIN	PVIN	-0.3	18	V
Supply voltage VCC	VCC	-0.3	5.5	V
VCC ramp time	VCC		20	ms
VDD33	VDD33	-0.3	3.6	V
Digital ground	DGND	-0.3	0.1	V
Power ground	PGND	-0.3	0.3	V
Digital I/O pins	SALRT, POK, SYNC,	-0.3	5.5	V
Digital I/O pins	SCL, SDA, CTRL	-0.3	3.6	V
Analog I/O pins	VINSEN, VCCSEN, ADDRO, ADDR1, RVSET, RTUNE, VTRACK	-0.3	2.0	V
Voltage feedback	VSENP, VSENN	-0.3	2.0	V
PWM pin	PWM	-0.3	5.5	V
Output voltage pins	VOUT	-0.3	5.5	V
DC current on VOUT	VOUT		23	А

Table 3

Absolute Maximum Thermal Ratings

PARAMETER	CONDITION	MIN	MAX	UNITS
Operating junction temperature			+125	°C
Storage temperature range		-65	+150	°C
Reflow peak body temperature	(10 Sec) MSL3		+260	°C

Absolute Maximum ESD Ratings

PARAMETER	CONDITION	MIN	MAX	UNITS
HBD	All pins; Except VINSEN 1000 V Max	2000		V
CDM; all pins		500		V

Recommended Operating Conditions

Table 4

PARAMETER	PINS	MIN	MAX	UNITS
PVIN supply voltage range	PVIN	4.5	16	V
Supply voltage V _{cc} & PV _{cc}	VCC, PVCC	4.75	5.25	V
Continuous load current	V _{OUT}		20	А

Thermal Characteristics

Table 5

PARAMETER	PINS	TYPICAL	UNITS
Thermal shutdown [programmable]	T _{SD}	120	°C
Thermal shutdown Hysteresis	T _{SDH}	18	°C
Thermal resistance: junction to ambient (0 LFM) (Note1)	$ heta_{JA}$	8	°C/W
Thermal resistance: junction to case bottom (0 LFM)	οl	1.5	°C/W

Note1: Based on 2 oz. external copper layers and proper thermal design in line with EIJ/JEDEC JESD51 standards for high thermal conductivity boards. No top side cooling required.

Electrical Characteristics

 PV_{IN} = 12V and V_{CC} = 5.0V. The minimum and maximum values are over the operating ambient temperature range (-40°C to 85°C) unless otherwise noted. Typical values are at T_A = 25°C.

		Table 6				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
		SUPPLY CHARACTERISTICS				
PVIN supply voltage range	PVIN		4.5		16	V
PVIN supply quiescent		Device switching; no load; f _{sw} = 800 kHz; V _{OUT} = 1.0V		40		mA
current		Device not switching		1		
VCC supply voltage range	VCC		4.75	5.0	5.25	V
VCC UVLO rising				4.4		V
VCC UVLO falling				4.2		V
		Normal operation; no load; f _{sw} = 800 kHz		80		mA
PVCC & VCC supply current		Normal operation; no load; f _{sw} = 1.33 MHz		120		mA
		Idle; communication and telemetry only; no switching		30		mA
		Disabled ($V_{CC} \le 2.8V$)		900		μA
	INTER	NALLY GENERATED SUPPLY VO	LTAGE			
VDD33 voltage range	VDD33		3.0	3.3	3.6	
VDD33 output current					2	mA
		DIGITAL I/O PINS (POK, SYNC)			I	
Input high voltage			2.0		5.5	V
Input low voltage			0		0.8	V
Output high voltage			2.4		VDD33	V
Output low voltage					0.4	V
Input leakage current					±1	μΑ
Output current - source					2.0	mA
Output current - sink					2.0	mA
		DIGITAL I/O PIN (CTRL)				
Input high voltage			2.0		3.6	V
Input low voltage			-0.3		0.8	V

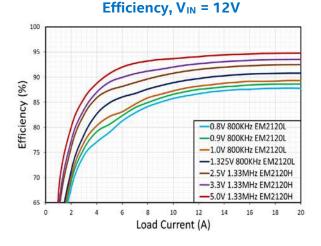
Table 6

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
CTRL response delay (stop)		Configurable polarity; extra turn-off delay configurable (assumes 0 s turn-off delay)		150		μs
CTRL response delay (start)		Configurable polarity; extra turn-on delay configurable (assumes 0 s turn-on delay)		250		μs
Н	KADC INPUT	PINS (VINSEN, VCCSEN, ADDRO	AND ADI	DR1)	1	
Input voltage			0		1.44	V
		PWM AND SYNCHRONIZATION				
PWM output voltage - high			2.4			V
PWM output voltage - low					0.4	V
PWM tristate leakage					±1	μΑ
PWM pulse width			30			ns
Resolution				163		ps
Switching frequency – EM2120L	f _{sw}	With internal oscillator		800		kHz
Switching frequency – EM2120H	f _{sw}	With internal oscillator		1333		kHz
SYNC frequency range		Percent of nominal switching frequency			±12.5	%
SYNC pulse width			25			ns
0	UTPUT VOLI	AGE SENSE, REPORTING, AND I	MANAGEM	1ENT		
Output voltage	EM2120L		0.7		1.325	V
adjustment range	EM2120H		1.35		5	V
	EM2120L	0°C < T _A < 85°C	-0.5		+0.5	%
Output voltage set- point accuracy	EM2120L	-40°C < T _A < 85°C	-1		+1	%
point accuracy	EM2120H	-40°C < T _A < 85°C	-1		+1	%
Output set-point resolution	EM2120L			1.5		mV
Line regulation				0.007		mV/V
Load regulation				0.07		mV/A
Output voltage startup delay		From V _{CC} valid, to start of output voltage ramp, if configured to regulate from power on reset, and TON_DELAY is set to 0.		5		ms

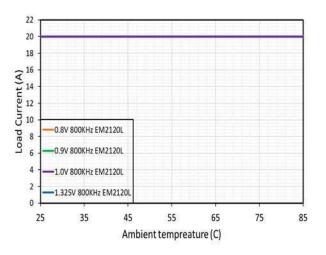
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output voltage ramp delay (TON_DELAY & TOFF_DELAY)		Configurable, no V _{OUT} pre- bias condition.	0		500	ms
Vout slew rate				0.5		V/ms
VTRACK ramp rate					2.0	V/ms
VTRACK range		Without resistor divider	0		1.4	V
VTRACK offset voltage				±100		mV
01	JTPUT CUR	RENT SENSE, REPORTING, AND I	ANAGEM	1ENT		
Current sense reporting		I _{OUT} > 5A, 25°C <u><</u> T _A < 85°C		±1.5		А
accuracy		I _{OUT} > 5A, T _A = 25°C		±1		А
-	TEMPERATU	RE SENSE, REPORTING, AND MA	NAGEME	NT		1
Temperature reporting accuracy				±5		°C
Resolution				0.22		°C
	FAULT I	MANAGEMENT PROTECTION FEA	ATURES			
PV _{IN} UV threshold				3.96		V
PVIN OV threshold				16.5		V
Vout OV threshold		Percentage of output voltage		115		%
V _{OUT} UV threshold		Percentage of output voltage		85		%
IOUT OCP		With 30A OCP setting	25		35	А
OTP threshold				120		°C
OTP hysteresis		Fixed.		85		%
POK threshold		On level		95		%
POK threshold		Off level		90		%
Watchdog Timer Interval					3	ms
9	SERIAL COM	MUNICATION PMBUS DC CHARA	CTERIST	ics		•
Input voltage – high (VIH)		SCL and SDA	1.11			V
Input voltage – low (VIL)		SCL and SDA			0.8	V
Rise & Fall Time		SCL and SDA >0.8V<1.1V			2	ms
Input leakage current		SCL, SDA, SALRT, and CTRL.	-10		10	μA
Output voltage – low (VOL)		SDA and SALRT at rated pull- up current of 20mA.			0.4	V
Nominal bus voltage		SCL, SDA, and SALRT termination voltage.			3.6	V

Typical Performance Characteristics

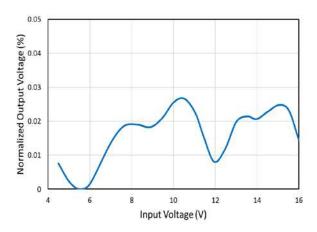
All the performance curves are measured with EM2120 evaluation board at 25°C ambient temperature unless otherwise noted. The output capacitors configuration for the evaluation board is 2 x 470 μ F (3 m Ω ESR) + 4 x 100 μ F (Ceramic) + 4 x 47 μ F (Ceramic) for EM2120L and 2 x 220 μ F (5 m Ω ESR) + 6 x 47 μ F (Ceramic) for EM2120H.



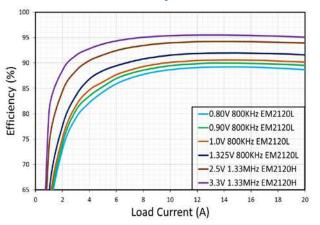
EM2120L Thermal Derating, No Airflow



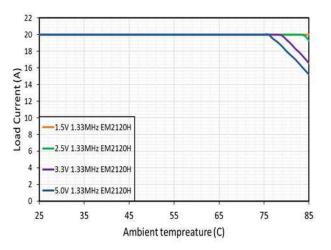
EM2120L Line Regulation, Vout = 0.9V



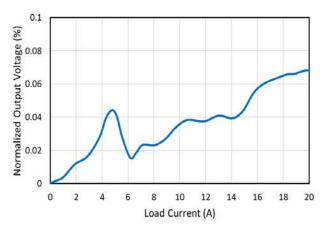
Efficiency, V_{IN} = 5V

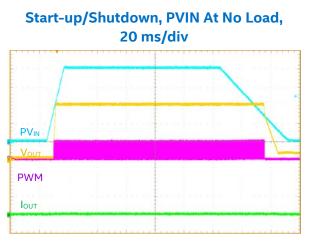


EM2120H Thermal Derating, No Airflow



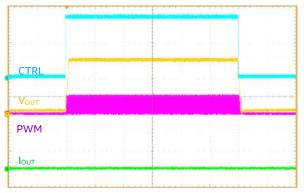
EM2120L Load Regulation, Vout = 0.9V





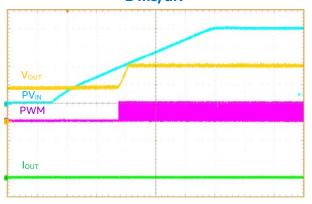
PV_{IN} and PWM: 3 V/div, V_{OUT}: 300 mV/div, I_{OUT}: 10 A/div

Start-up/Shutdown, CTRL At No Load, 10 ms/div



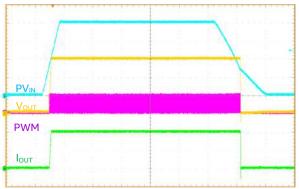
CTRL: 1 V/div, PWM: 3 V/div, V_{OUT}: 300 mV/div, I_{OUT}: 10 A/div





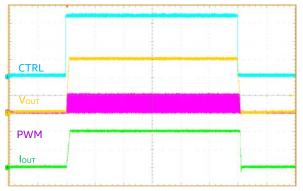
 $\label{eq:pvin} \begin{array}{l} \mathsf{PV}_{\mathsf{IN}} : \texttt{3 V/div}, \, \mathsf{PWM} : \texttt{3 V/div}, \\ \mathsf{V}_{\mathsf{OUT}} : \texttt{300 mV/div}, \, \mathsf{I}_{\mathsf{OUT}} : \texttt{10 A/div} \end{array}$





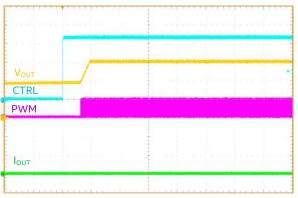
PV_{IN} and PWM: 3 V/div, V_{OUT}: 300 mV/div, I_{OUT}: 10 A/div

Start-up/Shutdown, CTRL At 20A Load, 10 ms/div



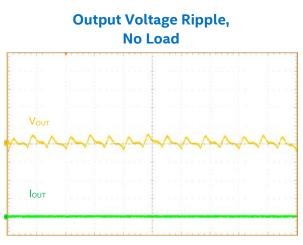
CTRL: 1 V/div, PWM: 3 V/div, V_{OUT}: 300 mV/div, I_{OUT}: 10 A/div

Start-up Into 0.6V Pre-Bias With CTRL, 2 ms/div



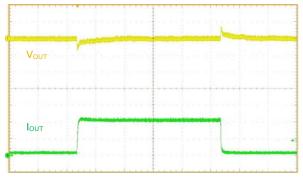
CTRL: 1 V/div, PWM: 3 V/div, V_{OUT}: 300 mV/div, I_{OUT}: 10 A/div

Data Sheet | Intel Enpirion Power Solutions: EM2120 Typical Performance Characteristics (Continued)



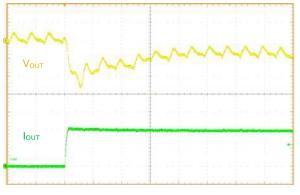
 V_{IN} = 12V, V_{OUT} = 0.9V 2 µs/div, V_{OUT} : 10 mV/div, 20 MHz bandwidth

Output Voltage Transient Response, Load Step From 0A To 10A

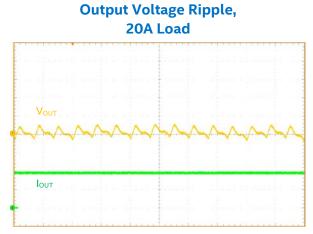


$$\label{eq:VIN} \begin{split} V_{IN} &= 12V, \, V_{OUT} = 0.9V, \, 100 \mu s/div \\ V_{OUT} &: 30mV/div, \, I_{OUT} &: 5A/div, \, 10A/\mu s \end{split}$$



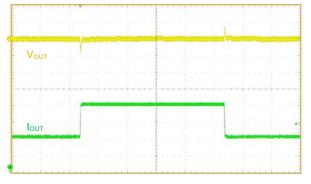


$$\label{eq:VIN} \begin{split} V_{\text{IN}} &= 12V, \, V_{\text{OUT}} = 0.9V, \, 2\mu s/div \\ V_{\text{OUT}} &: 10mV/div, \, I_{\text{OUT}} &: 5A/div, \, 10A/\mu s \end{split}$$



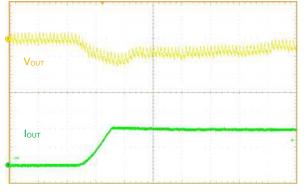
 V_{IN} = 12V, V_{OUT} = 0.9V 2 µs/div, V_{OUT} : 10 mV/div, 20 MHz bandwidth

Output Voltage Transient Response, Load Step From 10A To 20A



$$\label{eq:VIN} \begin{split} V_{IN} &= 12V, V_{OUT} = 0.9V, 100 \mu s/div \\ V_{OUT} &: 30 mV/div, I_{OUT} &: 5A/div, 10A/\mu s \end{split}$$

Output Voltage Transient Response, Load Step From 0A To 10A



$$\label{eq:VIN} \begin{split} V_{\text{IN}} &= 12V, V_{\text{OUT}} = 0.9V, 10\mu\text{s/div} \\ V_{\text{OUT}} &: 10 \text{ mV/div}, I_{\text{OUT}} &: 5\text{A/div}, 1\text{A/}\mu\text{s} \end{split}$$

Functional Block Diagram

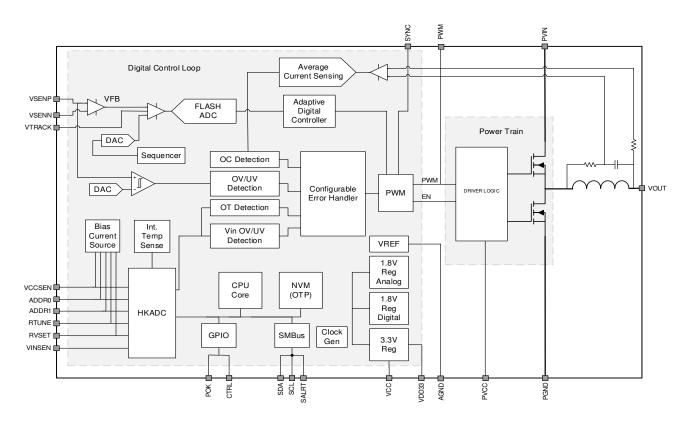


Figure 2: Functional Block Diagram

Functional Description

FUNCTIONAL DESCRIPTION: DEFAULT CONFIGURATION

The EM2120 is a single output digital PowerSoC synchronous step-down converter with advanced digital control techniques, capable of supplying up to 20A of continuous output current. The PowerSoC includes integrated power MOSFETs, a high-performance inductor and a digital controller which offers a PMBus version 1.2 compliant interface to support an extensive suite of telemetry, configuration and control commands.

In the default configuration, the EM2120 requires only two resistors total to set the output voltage and set the digital compensator for the most optimized performance. This easy-to-use default configuration allows the user to tune the EM2120 to meet the most demanding accuracy and load transient requirements without requiring any programming or digital interface. The following sections describe the default configuration. Refer to the Advanced Configuration section for details on the many ways the EM2120 may be customized and configured through the PMBus interface.

In order to optimize size versus efficiency over a wide range of operating conditions, there are two module variants – a low output voltage variant EM2120L01 (0.7V $\leq V_{OUT} \leq 1.325V$) which operates at 800KHz and a high output voltage variant EM2120H01 (1.35V $\leq V_{OUT} \leq 5V$) which operates at 1.33MHz.

The advanced digital control loop works as a voltage-mode controller using a PID-type compensation. The basic structure of the controller is shown in Figure 3. The EM2120 controller features two PID compensators for steady-state operation and fast transient operation. Fast, reliable switching between the different

compensation modes ensures good transient performance and quiet steady state performance. The EM2120 has been pre-programmed with a range of default compensation coefficients which lets the user select the best compensation for the best transient response and stability for the output capacitance of the system.

The EM2120 uses two additional technologies to improve transient performance. First, the EM2120 uses oversampling techniques to acquire fast, accurate, and continuous information about the output voltage so that the device can react quickly to any changes in output voltage. Second, a non-linear gain adjustment is applied during large load transients to boost the loop gain and reduce the settling time.

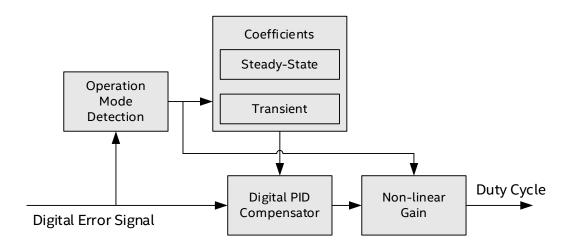


Figure 3: Simplified Block Diagram Of The Digital Compensation

In the default configuration, the EM2120 offers a complete suite of fault warnings and protections. Input and output Under Voltage Lock-Out (UVLO) and Over Voltage Lock-Out (OVLO) conditions are continuously monitored. A dedicated ADC is used to provide fast and accurate current information over the switching period allowing for fast Over-Current Protection (OCP) response. Over Temperature Protection (OTP) is accomplished by direct monitoring of the device's internal temperature.

POWER ON RESET

The EM2120 employs an internal power-on-reset (POR) circuit to ensure proper start-up and shut down with a changing supply voltage. Once the VCC supply voltage increases above the POR threshold voltage, the EM2120 begins the internal start-up process. Upon its completion, the device is ready for operation.

Two separate input voltage supplies are necessary to operate, PVIN (4.5V to 16V) and V_{CC} (4.75V to 5.25V). Both of these voltage rails must be monitored for proper power-up and to protect the power MOSFETs under various input power fault conditions. A voltage divider on each input voltage supply connected to VINSEN for the power rail (PVIN) and VCCSEN for the supply rail (VC) is used for digital monitoring of the supplies.

As illustrated in Figure 4, the values of resistors R1, R2, R3 and R4 are chosen so the internal monitor ADC does not saturate within the appropriate ranges. This allows the EM2120 telemetry to report when the recommended operation voltage has been exceeded.

It is mandatory that the listed resistors values are used in order to ensure proper operation with the EM2120 default configuration. The resistors used must be R1=11 k Ω , R2=1 k Ω , R3=10 k Ω and R4=3.3 k Ω , using 1% tolerance or better resistors. If these values are not used, then the EM2120 will read incorrect values for both PVIN and VCC.

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Digital filtering is provided inside the EM2120 but if additional filtering is needed due to high noise on either rail, a capacitor can be connected between each pin (VINSEN & VCCSEN) and ground to maintain high accuracy.

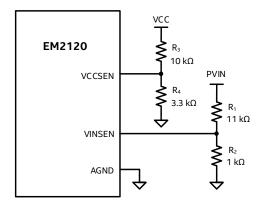


Figure 4: VINSEN And VCCSEN Input Resistor Dividers

The EM2120 also uses the PVIN monitor for input voltage feed-forward, which eliminates variations in the output voltage due to sudden changes in the input voltage supply. It does this by immediately changing the duty cycle to compensate for the input supply variation by normalizing the DC gain of the loop.

SETTING THE OUTPUT VOLTAGE

Differential remote sensing provides for precise regulation at the point of load. One of thirty output voltages may be selected in the default configuration, based on a resistor connected to the RVSET pin. At power-up, an internal current source biases the resistor and the voltage is measured by an ADC to decode the Vout selection. Use the RVSET tables (Table 8 and Table 9) for the details of VOUT selection and RVSET values.

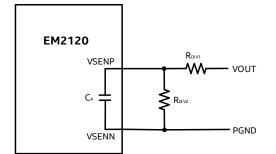


Figure 5: Output Voltage Sense Circuitry

The digital control loop ADC of the low voltage EM2120L01 supports direct output voltage feedback connection over the entire V_{OUT} range. For the high output voltage EM2120H01, a feedback divider is required as shown in Figure 5. The resistor values in Table 7 are required as a function of the output voltage selection. It is mandatory that the listed resistor values are used, use of other values may result in poor regulation performance as these values are expected in the EM2120 default configuration. Resistors with tight tolerances are recommended to maintain output voltage accuracy.

The resistors in the feedback path also form a low-pass filter with the internal capacitor, C_A , for removing high-frequency disturbances from the sense signals. Place these components as close as possible to the EM2120 for best filtering performance.

Module	V _{OUT}	R _{DIV1}	R _{DIV2}
EM2120L01	$0.7V \le V_{OUT} \le 1.325V$	2 kΩ	Open
EM2120H01	1.35V ≤ V _{OUT} ≤ 2.6V	2 kΩ	2 kΩ
EM2120H01	2.7V ≤ VOUT ≤ 3.8V	2 kΩ	1 kΩ
EM2120H01	$3.8V < V_{OUT} \le 5V$	2 kΩ	665Ω

Table 7: Output Voltage Feedback Component

Table 8: Supported Configuration Voltage Values For EM2120L01 Output Voltage

RVSET Resistor	V _{OUT}	External Resistor Divider
0kΩ	Reserved	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
0.392kΩ	Reserved	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
0.576kΩ	Reserved	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
0.787kΩ	Reserved	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
1.000kΩ	1.325V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
1.240kΩ	1.3V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
1.500kΩ	1.275V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
1.780kΩ	1.25V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
2.100kΩ	1.225V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
2.430kΩ	1.2V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
2.800kΩ	1.175V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
3.240kΩ	1.15V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
3.740kΩ	1.12V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
4.220kΩ	1.1V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
4.750kΩ	1.075V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
5.360kΩ	1.05V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
6.040kΩ	1.03V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
6.810kΩ	1.0V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
7.680kΩ	0.975V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
8.660kΩ	0.95V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
9.530kΩ	0.925V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
10.500kΩ	0.9V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
11.800kΩ	0.875V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
13.000kΩ	0.85V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
14.300kΩ	0.825V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
15.800kΩ	0.8V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
17.400kΩ	0.775V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$

RVSET Resistor	V _{OUT}	External Resistor Divider
19.100kΩ	0.75V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
21.000kΩ	0.725V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$
23.200kΩ	0.7V	$R_{1DIV} = 2k\Omega, R_{2DIV} = open$

Table 9: Supported Configuration Voltage Values For EM2120H01 Output Voltage

	<u> </u>	
RVSET Resistor	V _{OUT}	External Resistor Divider
0kΩ	Reserved	$R_{1DIV} = 2k\Omega, R_{2DIV} = 1k\Omega$
0.392kΩ	Reserved	$R_{1DIV} = 2k\Omega, R_{2DIV} = 1k\Omega$
0.576kΩ	3.3V	R_{1DIV} = 2k Ω , R_{2DIV} = 1k Ω
0.787kΩ	3.2V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 1k\Omega$
1.000kΩ	3.1V	R_{1DIV} = 2kΩ, R_{2DIV} = 1kΩ
1.240kΩ	3.0V	R_{1DIV} = 2k Ω , R_{2DIV} =1k Ω
1.500kΩ	2.9V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 1k\Omega$
1.780kΩ	2.8V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 1k\Omega$
2.100kΩ	2.7V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 1k\Omega$
2.430kΩ	2.6V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
2.800kΩ	2.5V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
3.240kΩ	2.4V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
3.740kΩ	2.3V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
4.220kΩ	2.2V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
4.750kΩ	2.1V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
5.360kΩ	2.0V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
6.040kΩ	1.9V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
6.810kΩ	1.8V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
7.680kΩ	1.75V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
8.660kΩ	1.7V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
9.530kΩ	1.65V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
10.500kΩ	1.6V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
11.800kΩ	1.55V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
13.000kΩ	1.5V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
14.300kΩ	1.475V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
15.800kΩ	1.45V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
17.400kΩ	1.425V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
19.100kΩ	1.4V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$

RVSET Resistor	V _{OUT}	External Resistor Divider
21.000kΩ	1.375V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$
23.200kΩ	1.35V	$R_{1DIV} = 2k\Omega, R_{2DIV} = 2k\Omega$

Note: For 5Vout operation select $2.8k\Omega$ as the RVSET value and use external voltage divider values of RDIV1 = $2k\Omega \& RDIV2 = 665\Omega$. In this instance for the Command READ_VOUT the read-back values need to be scaled up by a factor of 2.

ENABLE AND OUTPUT START-UP BEHAVIOR

The control pin (CTRL) provides a means to enable normal operation or to shut down th device. When the CTRL pin asserted (high) the device will undergo a normal soft-start. A logic low on this pin will power the device down in a controlled manner. Dedicated pre-biased start-up logic ensures proper start-up of the power converter when the output capacitors are pre-charged to a non-zero output voltage. Closed-loop stability is ensured during this period.

The typical power sequencing, including ramp up/down and delays is shown in Figure 6.

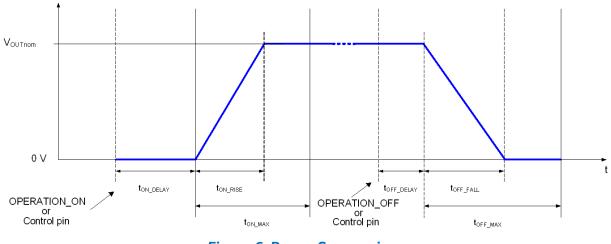


Figure 6: Power Sequencing

POWER OK

The EM2120 has a power good indicator at its output pin, POK. When de-asserted, POK indicates that the output voltage is below the threshold value, 90% of the programmed output voltage in the default configuration. When asserted, POK indicates that the output is in regulation, and no major faults are present. As a result, POK de-asserts during any serious fault condition where power conversion stops and re-asserts when the output voltage recovers.

The POK indication can be either push-pull or open-drain, selected based upon the PMBus[™] address. For addresses in the range 0x01 to 0x40, the POK signal is a push-pull output and no pull-up resistor is required. For addresses in the range 0x41 to 0x7F, the POK signal is open-drain and may be wire-OR's with other open drain signals with an appropriate pull-up resistor. The Pull-Up resistor may be connected to the VDD33 pin but it is not recommended to use the 5VCC supply. **Table 15** describes the resistor values which are used to set the PMBus address.

In a noisy application, it is strongly recommended that a 100nf decoupling capacitor be placed between the POK pin and GND to act as a filter to unwanted external noise. When configured as a Push-Pull output, a $10k\Omega$ pull-down resistor to Gnd may be used instead to prevent any spurious noise spikes appearing on POK upon power being applied to the module.

COMPENSATING THE DIGITAL CONTROL LOOP

To improve the transient performance for a typical point-of-load design, it is common to add output capacitance to the converter. This moves the output LC resonant frequency lower as capacitance increases which results in lower bandwidth, lower phase margin, and longer settling times unless the control loop is compensated for added capacitance.

However, with EM2120 the user does not need to be concerned with, or even understand, the details of control loop compensation techniques. The default configuration allows users to select from preconfigured PID control loop settings (known as compensators) through the use of pin-strapping. A single resistor from the RTUNE pin to AGND informs the EM2120 of the compensator selection.

The selection of the compensator is driven first by the type of output capacitors used, as the ESL and ESR of different capacitor types demands different PID coefficients to optimize transient deviation and recovery characteristics. An all ceramic output capacitor design requires a different compensator than a design with a combination of ceramic and polymer capacitors, i.e. POSCAP. **Table 12** shows several output capacitor part number recommendations.

The five different compensators can then be subdivided into groups of six each whereby the initial capacitance value in the appropriate compensator can be scaled upwards by multiplication factor M to match the additional capacitance.

Table 10: RTUNE configuration table for EM2120L01

Compensator Description	Соит	RTUNE Resistor	Multiplication factor (M)	Typical Deviation With 50% Load Step
Polymer Aluminum (SP-CAP) and Ceramic MLCC Output	Base	0kΩ	1	± 5%
	2 x Base	0.392kΩ	2	± 3%
Capacitors	3 x Base	0.576kΩ	3	
Base capacitance = 1 x 470µF	4 x Base	0.787kΩ	4	± 1.5%
(Polymer) + 2 x 100µF (Ceramic) + 2 x 47µF (Ceramic)	5 x Base	1.000kΩ	5	
$(Ceramic) + 2 \times 47 \mu r (Ceramic)$	6 x Base	1.240kΩ	6	
	Base	1.500kΩ	1	± 5%
	1.5 x Base	1.780kΩ	1.5	
All MLCC Ceramic Output Capacitors	2 x Base	2.100kΩ	2	± 3%
Base capacitance = 8 x 100µF	3 x Base	2.430kΩ	3	
	4 x Base	2.800kΩ	4	
	4.5 x Base	3.240kΩ	4.5	± 1.5%
	Base	3.740kΩ	1	± 5%
POSCAP and Ceramic MLCC	1.5 x Base	4.220kΩ	1.5	
Output Capacitors	2 x Base	4.750kΩ	2	± 3%
Base capacitance = 4 x 330 μF (POSCAP) + 2 x 100 μF	2.5 x Base	5.360kΩ	2.5	
(Ceramic)	3 x Base	6.040kΩ	3	± 1.5%
	3.5 x Base	6.810kΩ	3.5	
		7.680kΩ		
		8.660kΩ		
		9.530kΩ		
		10.500kΩ		
		11.800kΩ		
Reserved for User Programmed Compensation		13.000kΩ		
Values		14.300kΩ		
		15.800kΩ		
		17.400kΩ		
		19.100kΩ		
		21.000 kΩ		
		23.200 kΩ		

Table 11: RTUNE configuration table for EM2120H01

Compensator Description	Соит	RTUNE Resistor	Multiplication factor (M)	Typical Deviation With 10A Load Step
Polymer Aluminum (SP-CAP)	Base	0kΩ	1	± 3%
	2 x Base	0.392kΩ	2	
and Ceramic MLCC Output Capacitors	2.5 x Base	0.576kΩ	2.5	
Base capacitance = 2 x 220µF	3 x Base	0.787kΩ	3	
(Polymer) + 6 x 47µF	3.5 x Base	1.000kΩ	3.5	
	4 x Base	1.240kΩ	4	
	Base	1.500kΩ	1	± 3%
	1.5 x Base	1.780kΩ	1.5	
All MLCC Ceramic Output Capacitors	2 x Base	2.100kΩ	2	
Base capacitance = 10 x 100µF	2.5 x Base	2.430kΩ	2.5	
	3 x Base	2.800kΩ	3	
	3.5 x Base	3.240kΩ	3.5	
	Base	3.740kΩ	1	
TANT-CAP and Ceramic	2 x Base	4.220kΩ	2	± 3%
MLCC Output Capacitors	2.5 x Base	4.750kΩ	2.5	
Base capacitance = 1 x 470µF (TANT) + 2 x 100µF (Ceramic) +	3 x Base	5.360kΩ	3	
$2 \times 47 \mu F$ (Ceramic)	3.5 x Base	6.040kΩ	3.5	
	4 x Base	6.810kΩ	4	
		7.680kΩ		
		8.660kΩ		
		9.530kΩ		
		10.500kΩ		
		11.800kΩ		
Reserved for User		13.000kΩ		
Programmed Compensation Values		14.300kΩ		
		15.800kΩ		
		17.400kΩ		
		19.100kΩ		
		21.000 kΩ		
		23.200 kΩ		

Description	Manufacture r	P/N
470μF, 2.5V, ESR 3mΩ SP-CAP	Panasonic	EEFGX0E471R
470 μ F, 10V, ESR 50mΩ CAP-TANT (Note3)	AVX Corp	TPSE477K010R0050
330μ F, 6.3V, ESR 9 m Ω POSCAP	Panasonic	6TPF330M9L
220 μ F, 6.3V, ESR 5 m Ω POSCAP	Panasonic	6TPF220M5L
330μ F, 2.5V, ESR 9 m Ω POSCAP	Kemet	T520B337M2R5ATE009
100µF, 6.3V, X5R, 1206 Ceramic	Kemet	C1206C107M9PACTU
100µF, 10V, X5R, 1206 Ceramic (Note3)	TDK	C3216X5R1A107M
47µF, 6.3V, X5R 1206 Ceramic	Murata	GRM31CR60J476ME19L
47µF, 10V, X5R 1206 Ceramic (Note3)	Kemet	C1206C476M8PACTU

 Table 12: Recommended Output Capacitors

Note3: These caps used for EM2120H01 Comp2 to support 5V out

OUTPUT CAPACITOR RECOMMENDATION

EM2120 is designed for fast transient response and low output ripple noise. The output capacitors should be low ESR polymer, tantalum or ceramic capacitor. **Table 10** shows different output capacitor combinations to optimize the load transient deviation performance. With the Rtune feature, the user can simply scale up the total output capacitance to meet further stringent transient requirement.

Please consult the documentation for your particular FPGA, ASIC, processor, or memory block for the transient and the bulk decoupling capacitor requirements.

INPUT CAPACITOR RECOMMENDATION

The EM2120 input should be decoupled with at least three 22μ F 1206 case size and one 10μ F 0805 case size MLCC ceramic capacitors or four 22μ F MLCC 1206 case size ceramic capacitors. More bulk capacitor may be needed only if there are long inductive traces at the input source or there is not enough source capacitance.

These input decoupling ceramic capacitors can be mounted on the PCB back-side to reduce the solution size. These input filter capacitors should have the appropriate voltage rating for the input voltage on PVIN, and use a X5R, X7R, or equivalent dielectric rating. Y5V or equivalent dielectric formulations must not be used as these lose too much capacitance with frequency, temperature and bias voltage.

The PVCC pin provides power to the gate drive of the internal high/low side power MOSFETs. The VCC pin provides power to the internal digital controller. These two power inputs share the same supply voltage (5V nominal), and should be bypassed with a single 2.2μ F MLCC capacitor. To avoid switching noise injection from PVCC to VCC, it is recommended a ferrite bead is inserted between PVCC and VCC pins as shown Figure 15.

Data Sheet | Intel Enpirion Power Solutions: EM2120 PROTECTION FEATURES

The EM2120 offers a complete suite of programmable fault warnings and protections. Input and output Under Voltage Lock-Out (UVLO) and Over Voltage Lock-Out (OVLO) conditions are continuously monitored. A dedicated ADC is used to provide fast and accurate current information during the entire switching period to provide fast Over-Current Protection (OCP) response.

To prevent damage to the load, the EM2120 utilizes an output over-voltage protection circuit. The voltage at VSENP is continuously compared with a configurable threshold using a high-speed analog comparator. If the voltage exceeds the configured threshold, a fault response is generated and the PWM output is turned off.

The output voltage is also sampled, filtered, and compared with an output over-voltage warning threshold. If the output voltage exceeds this threshold, a warning is generated and the preconfigured actions are triggered. The EM2120 also monitors the output voltage with two lower thresholds. If the output voltage is below the under-voltage warning level and above the under-voltage fault level, an output voltage under-voltage warning is triggered. If the output voltage falls below the fault level, a fault event is generated.

Similar to output over and under voltage protection, the EM2120 monitors the input voltage at VINSEN continuously with a configurable threshold. If the input voltage exceeds the over voltage threshold or is below the under-voltage threshold, the default response is generated.

Over Temperature Protection (OTP) is based on direct monitoring of the device's internal temperature. If the temperature exceeds the OTP threshold, the device will enter a soft-stop mode slowly ramping the output voltage down until the temperature falls below the default recovery temperature.

The default fault response is zero delay and latch off for most fault conditions. The CTRL pin may be cycled to clear the latch. Table 13 summarizes the default configurations that have been pre-programmed to the device.

Signal	Fault Level	Default Response Type	Delay (ms)	Retries
	Warning		0	Nora
Output Over-Voltage	Fault	High-impedance	0	None
	Warning		0	None
Output Under-Voltage	Fault	High-impedance	0	
Input Over Voltage	Warning		0	None
Input Over-Voltage	Fault	High-impedance	0	
Input Under-Voltage	Warning		0	Infinity
	Fault	High-impedance	0	
Over-Current	Warning		0	None
	Fault	High-impedance	0	
Internal Over- Temperature	Warning		0	Infinity
	Fault	Soft Off	0	ппппту

Table 13: Fault Configuration Overview

FUNCTIONAL DESCRIPTION: ADVANCED CONFIGURATION

All EM2120 modules are delivered with a pre-programmed default configuration, allowing the module to be powered up without a need to configure the device or even the need for the GUI to be connected. However, a PMBus version 1.2 compliant interface allows access to an extensive suite of digital communication and control commands. This includes configuring the EM2120 for optimum performance, setting various parameters such as output voltage, and monitoring and reporting device behavior including output voltage, output current, and fault responses.

The device may be reconfigured multiple times without storing the configuration into the non-volatile memory (NVM). Any configuration changes will be lost upon power-on reset unless specifically stored into NVM using either STORE_DEFAULT_ALL or STORE_DEFAULT_CODE PMBus commands. Please see **Table 16** for more details.

For RVSET and RTUNE configurations, there is no reprogramming permitted.

After writing a new configuration to NVM, the user may still make changes to the device configuration through the PMBus interface; however, now upon power cycling the device, the stored NVM configuration will be recalled upon power-up rather than the factory default configuration of the EM2120.

The NVM configuration can be stored three times in its entirety. However, the consumption of the available NVM is dynamic, based on the configuration parameters that have actually changed. The unused NVM information is given in the GUI or through the manufacture specific command MFR_STORE_PARAMS_REMAINING.

INTEL DIGITAL POWER CONFIGURATOR

The Intel Enpirion Digital Power Configurator is a Graphical User Interface (GUI) software which allows the EM2120 to be controlled via a USB interface to a host computer.

The user can view the power supply's status, I/O voltages, output current and fault conditions detected by the device, program settings to the converter, and issue PMBus commands using the GUI. Most of the parameters (for example, VOUT turn on/off time, protection and fault limits) can be configured and adjusted within the GUI environment. These parameters can also be configured outside of the GUI environment using the relevant PMBus[™] commands.

The GUI also allows the user to easily create, modify, test and save a configuration file which may then be used to permanently burn the configuration into NVM within a production test environment.

ALTERNATIVE OUTPUT VOLTAGE CONTROL METHODS

In the default configuration, output voltage selection is determined at power-up by the pin-strapped resistor RVSET. This functionality can be disabled using the PMBus command MFR_PIN_CONFIG. When RVSET is disabled, the output voltage will be determined by the nominal output voltage setting in the user configuration. The EM2120 supports a subset of the output voltage commands outlined in the PMBus specification. For example, the output voltage can be dynamically changed using the PMBus command VOUT_COMMAND. When the output is being changed by the PMBus command, power good (POK) remains at a logic high.